Diode Semiconductor Device - Page 1 of 1

AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-050-7303
Inclosure Material:
Glass
Overall Length:
Between 0.230 inches and 0.300 inches
Overall Diameter:
Between 0.085 inches and 0.107 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
6.2 regulator voltage
Current Rating Per Characteristic:
15.00 amperes forward current, total rms any acceptable
Power Rating Per Characteristic:
250.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
Tolerance 5 pct
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0